## CY74FCT821T 10-BIT BUS-INTERFACE REGISTER WITH 3-STATE OUTPUTS

SCCS033B- MAY 1994 - REVISED NOVEMBER 2001

- Function, Pinout, and Drive Compatible With FCT, F Logic, and AM29821
- Reduced V<sub>OH</sub> (Typically = 3.3 V) Version of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)
- 64-mA Output Sink Current
  32-mA Output Source Current
- High-Speed Parallel Register With Positive-Edge-Triggered D-Type Flip-Flops
- 3-State Outputs

#### (TOP VIEW) 24 🛮 V<sub>CC</sub> OE II 23 X Y<sub>0</sub> $D_0 \square 2$ $D_1 \square 3$ 22 X1 $D_2 \square 4$ 21 Y<sub>2</sub> 20 TY3 $D_3 \square 5$ D<sub>4</sub> **[**] 6 19 Y<sub>4</sub> D<sub>5</sub> [] 7 18 Y<sub>5</sub> $D_6 \square 8$ 17 Y<sub>6</sub> $D_7 \begin{bmatrix} 1 \\ 9 \end{bmatrix}$ 16 Y<sub>7</sub> D<sub>8</sub> 10 15 Y<sub>8</sub> D<sub>9</sub> [ 11 14 Y<sub>9</sub> GND [] 12 13 CP

P, Q, OR SO PACKAGE

## description

This bus-interface register is designed to eliminate the extra packages required to buffer existing registers and provide extra data width for wider address/data paths or buses carrying parity. The CY74FCT821T is a 10-bit-wide buffered version of the popular CY74FCT374 function. This device is ideal for use as an output port requiring high I<sub>OL</sub>/I<sub>OH</sub>.

This device is designed for high-capacitance load drive capability, while providing low-capacitance bus loading at both inputs and outputs. Outputs are designed for low-capacitance bus loading in the high-impedance state.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### PIN DESCRIPTION

NAME	1/0	DESCRIPTION
D	_	D flip-flop data inputs
СР	0	Clock pulse for the register. Enters data into the register on the low-to-high clock transition.
Υ	0	Register 3-state outputs
ŌE	I	Output control. When $\overline{OE}$ is high, the Y outputs are in the high-impedance state. When $\overline{OE}$ is low, true register data is present at the Y outputs.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



#### **ORDERING INFORMATION**

TA	PAC	KAGE <sup>†</sup>	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP – Q	Tape and reel	6	CY74FCT821CTQCT	FCT821C
	SOIC - SO	Tube	6	CY74FCT821CTSOC	FCT821C
	3010 - 30	Tape and reel	6	CY74FCT821CTSOCT	FC1021C
	DIP – P	Tube	7.5	CY74FCT821BTPC	CY74FCT821BTPC
–40°C to 85°C	SOIC - SO	Tube	7.5	CY74FCT821BTSOC	FCT821B
	3010 - 30	Tape and reel	7.5	CY74FCT821BTSOCT	FC1021B
	QSOP – Q	Tape and reel	10	CY74FCT821ATQCT	FCT821A
	SOIC - SO	Tube	10	CY74FCT821ATSOC	FCT821A
	3010 - 30	Tape and reel	10	CY74FCT821ATSOCT	FUIOZIA

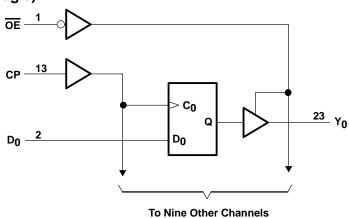
<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **FUNCTION TABLE**

	INPUTS			RNAL PUTS	FUNCTION		
OE	D	СР	Q	Υ			
Н	Χ	1	L	Z	Z		
Н	L	1	L	Z			
Н	Н	$\uparrow$	Н	Z	Lood		
L	L	$\uparrow$	L	L	Load		
L	Н	$\uparrow$	Н	Н			

H = High logic level, L = Low logic level, X = Don't care,  $\uparrow$  = Low-to-high transition, Z = High-impedance state

## logic diagram (positive logic)





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### absolute maximum rating over operating free-air temperature range (unless otherwise noted)

Supply voltage range to ground potential	0.5	V to 7 V
DC input voltage range		
DC output voltage range		
DC output current (maximum sink current/pin)		
Package thermal impedance, θ <sub>JA</sub> (see Note 1): P package		
(see Note 2): Q package		
(see Note 2): SO package		46°C/W
Ambient temperature range with power applied, T <sub>A</sub>	-65°C	to 135°C
Storage temperature range, T <sub>stg</sub>	-65°C 1	to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### recommended operating conditions (see Note 3)

		MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.75	5	5.25	V
VIH	High-level input voltage	2			V
V <sub>IL</sub>	Low-level input voltage			0.8	V
ІОН	High-level output current			-32	mA
lOL	Low-level output current			64	mA
TA	Operating free-air temperature	-40		85	°C

NOTE 3: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation.



NOTES: 1. The package thermal impedance is calculated in accordance with JESD 51-3.

<sup>2.</sup> The package thermal impedance is calculated in accordance with JESD 51-7.

## CY74FCT821T 10-BIT BUS-INTERFACE REGISTER WITH 3-STATE OUTPUTS

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## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITION	s	MIN	TYP <sup>†</sup>	MAX	UNIT
VIK	V <sub>CC</sub> = 4.75 V,	I <sub>IN</sub> = -18 mA			-0.7	-1.2	V
V	V 475 V	I <sub>OH</sub> = -32 mA		2			V
VOH	V <sub>CC</sub> = 4.75 V	I <sub>OH</sub> = -15 mA		2.4	3.3		V
VOL	V <sub>CC</sub> = 4.75 V,	I <sub>OL</sub> = 64 mA			0.3	0.55	V
V <sub>hys</sub>	All inputs				0.2		V
lj	V <sub>CC</sub> = 5.25 V,	V <sub>IN</sub> = V <sub>CC</sub>				5	μΑ
lіН	V <sub>CC</sub> = 5.25 V,	V <sub>IN</sub> = 2.7 V				±1	μΑ
Ι <sub>Ι</sub> L	V <sub>CC</sub> = 5.25 V,	$V_{IN} = 0.5 V$				±1	μΑ
lozh	V <sub>CC</sub> = 5.25 V,	V <sub>OUT</sub> = 2.7 V				10	μΑ
lozL	V <sub>CC</sub> = 5.25 V,	V <sub>OUT</sub> = 0.5 V				-10	μΑ
los <sup>‡</sup>	V <sub>CC</sub> = 5.25 V,	V <sub>OUT</sub> = 0 V		-60	-120	-225	mA
l <sub>off</sub>	$V_{CC} = 0 V$ ,	V <sub>OUT</sub> = 4.5 V				±1	μΑ
Icc	$V_{CC} = 5.25 \text{ V},$	$V_{IN} \le 0.2 V$ ,	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.1	0.2	mA
ΔlCC	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> =	3.4 V <sup>§</sup> , f <sub>1</sub> = 0, Outputs op	oen		0.5	2	mA
I <sub>CCD</sub> ¶	$\frac{V_{CC} = 5.25 \text{ V, One b}}{\text{OE} = \text{EN} = \text{GND, V}_{IN}}$	it switching at 50% duty c $1 \le 0.2 \text{ V or V}_{IN} \ge \text{V}_{CC} = 0$	cycle, Outputs open, 0.2 V		0.06	0.12	mA/ MHz
		One bit switching at f <sub>1</sub> = 5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4	
\#	$V_{CC} = 5.25 \text{ V},$	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1.2	3.4	A
IC#	Outputs open, OE = EN = GND	Eight bits switching at f <sub>1</sub> = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or} $ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		1.6	3.2	mA
		at 50% duty cycle	V <sub>IN</sub> = 3.4 V or GND		3.9	12.2	
C <sub>i</sub>					5	10	pF
Co					9	12	pF

<sup>&</sup>lt;sup>†</sup> Typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

IC = Total supply current

I<sub>CC</sub> = Power-supply current with CMOS input levels

ΔICC = Power-supply current for a TTL high input (V<sub>IN</sub> = 3.4 V)

 $D_H$  = Duty cycle for TTL inputs high  $N_T$  = Number of TTL inputs at  $D_H$ 

I<sub>CCD</sub> = Dynamic current caused by an input transition pair (HLH or LHL)

f<sub>0</sub> = Clock frequency for registered devices, otherwise zero

f<sub>1</sub> = Input signal frequency

N<sub>1</sub> = Number of inputs changing at f<sub>1</sub>

All currents are in milliamperes and all frequencies are in megahertz.

Values for these conditions are examples of the I<sub>CC</sub> formula.



Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, IOS tests should be performed last.

<sup>§</sup> Per TTL-driven input (V<sub>IN</sub> = 3.4 V); all other inputs at V<sub>CC</sub> or GND

This parameter is derived for use in total power-supply calculations.

<sup>#</sup> I<sub>C</sub> = I<sub>CC</sub> +  $\Delta$ I<sub>CC</sub> × D<sub>H</sub> × N<sub>T</sub> + I<sub>CCD</sub> (f<sub>0</sub>/2 + f<sub>1</sub> × N<sub>1</sub>) Where:

## **CY74FCT821T 10-BIT BUS-INTERFACE REGISTER** WITH 3-STATE OUTPUTS SCCS033B-MAY 1994 - REVISED NOVEMBER 2001

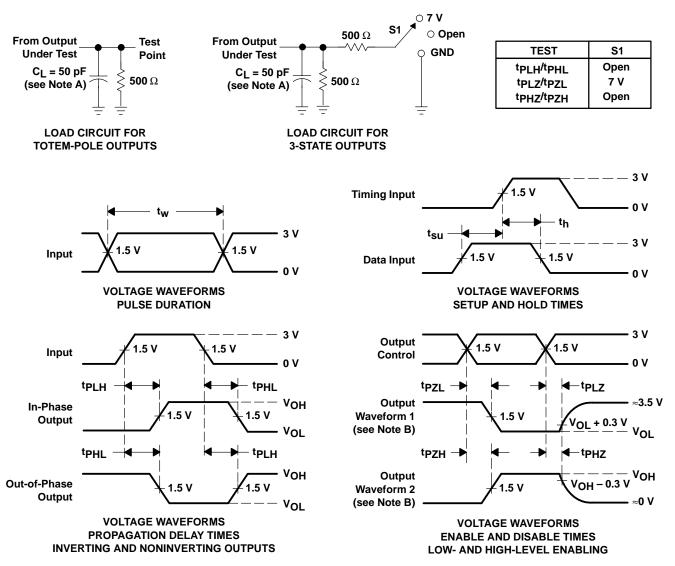
# timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

	PARAMETER	TEST LOAD	CY74FCT821AT		CY74FCT821BT		CY74FCT821CT		UNIT	
	PARAMETER	TEST LOAD	MIN	MAX	MIN	MAX	MIN	MAX	UNIT	
t <sub>W</sub>	Pulse duration	СР	$C_L = 50 \text{ pF},$ $R_L = 500 \Omega$	7		6		6		ns
t <sub>su</sub>	Setup time, before CP↑	Data	$C_L = 50 \text{ pF},$ $R_L = 500 \Omega$	4		3		3		ns
th	Hold time, after CP↑	Data	$C_L = 50 \text{ pF},$ $R_L = 500 \Omega$	2		1.5		1.5		ns

## switching characteristics over operating free-air temperature range (see Figure 1)

DADAMETER	FROM	то	TEST LOAD	CY74FC1	821AT	CY74FCT	821BT	CY74FC1	821CT	UNIT
PARAMETER	(INPUT)	(OUTPUT)	TEST LOAD	MIN	MAX	MIN	MAX	MIN	MAX	UNII
tPLH	СР	Υ	C <sub>L</sub> = 50 pF,		10		7.5		6	ns
t <sub>PHL</sub>	5	ī	$R_L = 500 \Omega$		10		7.5		6	115
tPLH	СР	Y	C <sub>L</sub> = 300 pF,		20		15		12.5	ns
t <sub>PHL</sub>	GF .	'	$R_L = 500 \Omega$		20		15		12.5	115
<sup>t</sup> PZH	ŌE	Υ	$C_L = 50 \text{ pF},$		12		8		7	ns
tPZL	OL	,	$R_L = 500 \Omega$		12		8		7	115
<sup>t</sup> PZH	OE	Y	$C_L = 300 \text{ pF},$		23		15		12.5	ns
tpzL	OL	'	$R_L = 500 \Omega$		23		15		12.5	110
t <sub>PHZ</sub>	ŌE	Υ	C <sub>L</sub> = 5 pF,		7		6.5		6	ns
tPLZ	) 	'	$R_L = 500 \Omega$		7		6.5		6	115
<sup>t</sup> PHZ	ŌĒ	Υ	$C_L = 50 \text{ pF},$		8		7.5		6.5	ns
tPLZ	) U	<u>'</u>	$R_L = 500 \Omega$		8		7.5		6.5	115

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>I</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms









## **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CY74FCT821ATQCT	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT821ATQCTE4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT821ATQCTG4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT821ATSOC	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821ATSOCE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821ATSOCG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821ATSOCT	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821ATSOCTE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821ATSOCTG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821BTPC	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT821BTPCE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT821BTSOC	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821BTSOCE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821BTSOCG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821BTSOCT	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821BTSOCTE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821BTSOCTG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821CTQCT	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT821CTQCTE4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT821CTQCTG4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT821CTSOC	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821CTSOCE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821CTSOCG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821CTSOCT	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT821CTSOCTE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM



#### PACKAGE OPTION ADDENDUM

21-May-2007

Orderable Device	Status (1)	Package Type	Package Drawing	Pins P	ackage Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CY74FCT821CTSOCTG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

 $^{(1)}$  The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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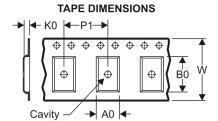




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#### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT821ATQCT	SSOP/ QSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT821ATSOCT	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CY74FCT821BTSOCT	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CY74FCT821CTQCT	SSOP/ QSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT821CTSOCT	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1





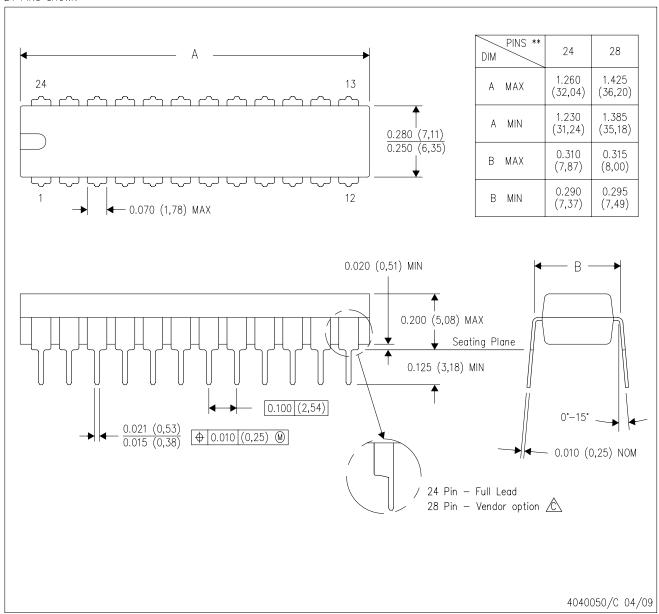
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT821ATQCT	SSOP/QSOP	DBQ	24	2500	346.0	346.0	33.0
CY74FCT821ATSOCT	SOIC	DW	24	2000	346.0	346.0	41.0
CY74FCT821BTSOCT	SOIC	DW	24	2000	346.0	346.0	41.0
CY74FCT821CTQCT	SSOP/QSOP	DBQ	24	2500	346.0	346.0	33.0
CY74FCT821CTSOCT	SOIC	DW	24	2000	346.0	346.0	41.0

## NT (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

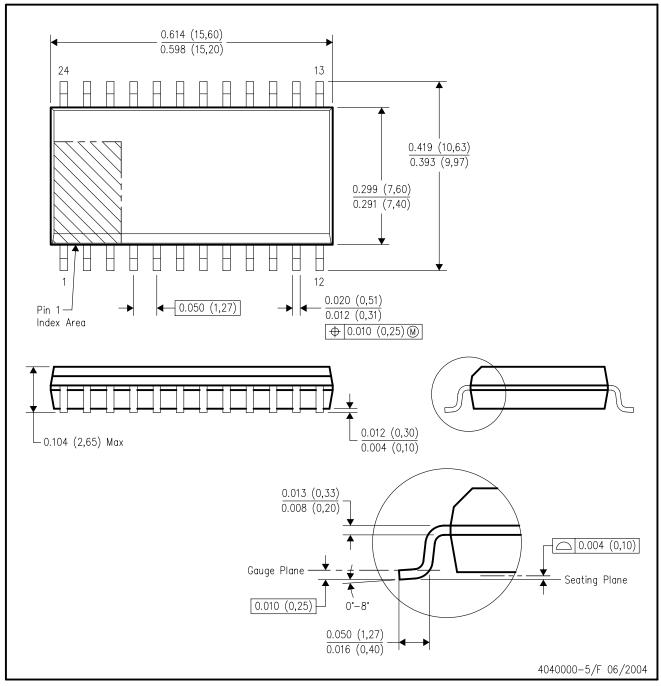
B. This drawing is subject to change without notice.

The 28 pin end lead shoulder width is a vendor option, either half or full width.



## DW (R-PDSO-G24)

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



DBQ (R-PDSO-G24)

## PLASTIC SMALL-OUTLINE PACKAGE



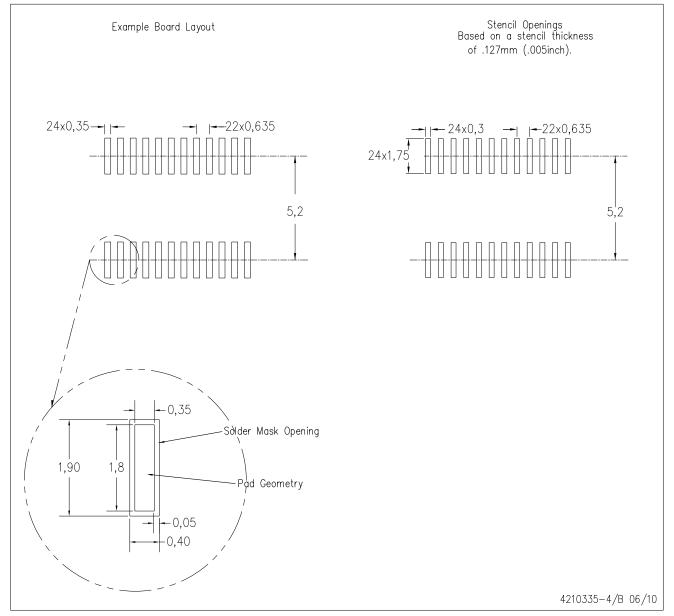
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AE.



DBQ (R-PDSO-G24)

## PLASTIC SMALL OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



#### IMPORTANT NOTICE

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